

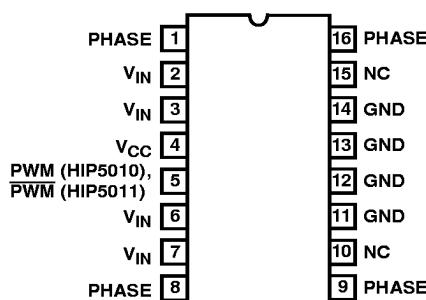
7V, 17A SynchroFET™ Complementary Drive Synchronous Half-Bridge

Designed with the P6 and Pentium in mind, the Harris SynchroFET™ family provides a new approach for implementing a synchronous rectified buck switching regulator. The SynchroFET™ replaces two power DMOSs, a Schottky diode, two gate drivers and synchronous control circuitry. The complementary drive circuit turns the upper FET on and the lower FET off when the input from the PWM is high. When the input from the PWM goes low the upper FET turns off and the lower FET turns on. The HIP5011 has a PWM pin that inverts the relationship from the input to PHASE. This architecture allows the designer to utilize a low cost single-ended PWM controller in either a current or voltage mode configuration. The SynchroFET™ operates in continuous conduction mode reducing EMI constraints and enabling high bandwidth operation. Several features ensure easy start-up. First, the supply currents stay below specification as the supply voltages ramp up; no unexpected surges occur that might perturb a soft-start or deplete a charge-pump. Second, any power-up sequence of the V_{CC} , V_{IN} , or PWM pins can be used without causing large currents. Third, the chip operates when V_{CC} is greater than 2V so V_{CC} can be created from a charge pump powered from V_{IN} .

Pinouts

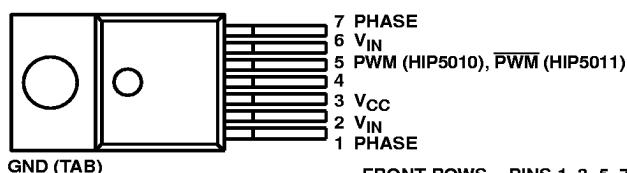
HIP5010IB, HIP5011IB (SOIC)

TOP VIEW



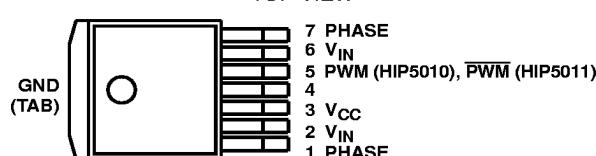
HIP5010IS1, HIP5011IS1 (SIP - VERTICAL)

TOP VIEW



HIP5010IS, HIP5011IS (SIP - GULLWING)

TOP VIEW



Features

- Complementary Drive, Half-Bridge Power NMOS
- Use With Low-Cost Single-Output PWM Controllers
- Improve Efficiency Over Conventional Buck Converter With Schottky Clamp
- Minimum Deadtime Provided by Adaptive Shoot-Through Protection Eliminates External Schottky
- Grounded Case for Low EMI and Simple Heatsinking
- Low Operating Current
- Frequency Exceeding 1MHz
- Dual Polarity Input Options
- All Pins Surge Protected

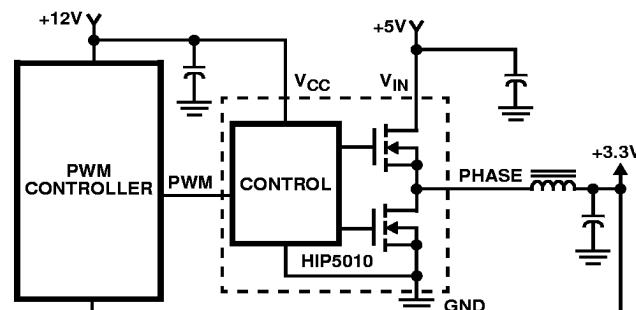
Applications

- 5V to \leq 3.3V Synchronous Buck Converters
- Pentium™ and P6™ Power Supplies
- PowerPC™ Power Supplies
- Bus Terminations (BTL and GTL)
- Drive 5V Motors Directly from Microprocessor

Ordering Information

| PART NUMBER | TEMP. RANGE (°C) | PACKAGE | PKG. NO. |
|-------------|------------------|-----------------------------|----------|
| HIP5010IB | -40 to 85 | 16 Ld Plastic SOIC (W) | M16.3 |
| HIP5010IS | -40 to 85 | 7 Ld Gullwing SIP | Z7.05B |
| HIP5010IS1 | -40 to 85 | 7 Ld Staggered Vertical SIP | Z7.05C |
| HIP5011IB | -40 to 85 | 16 Ld Plastic SOIC (W) | M16.3 |
| HIP5011IS | -40 to 85 | 7 Ld Gullwing SIP | Z7.05B |
| HIP5011IS1 | -40 to 85 | 7 Ld Staggered Vertical SIP | Z7.05C |

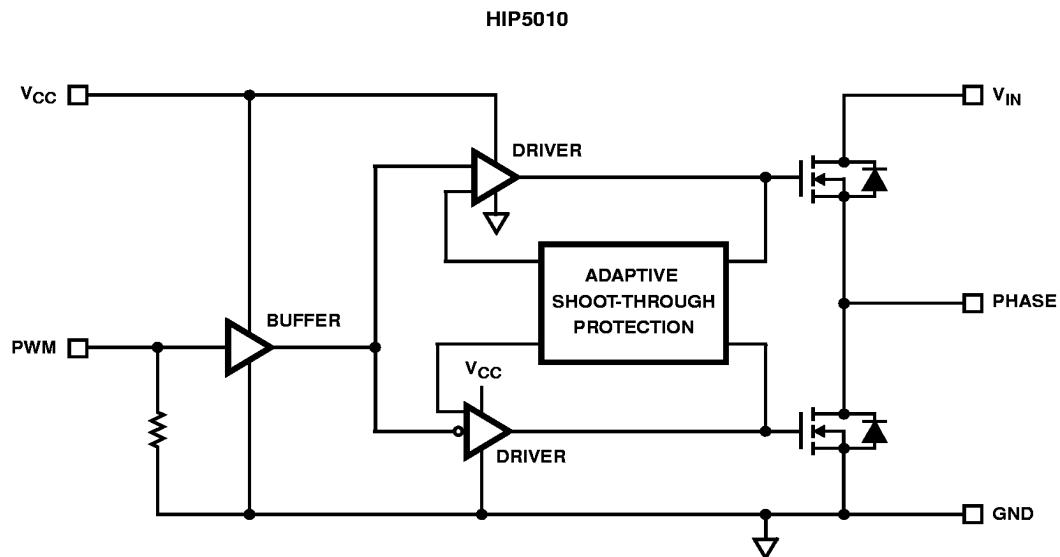
Typical Application Block Diagram



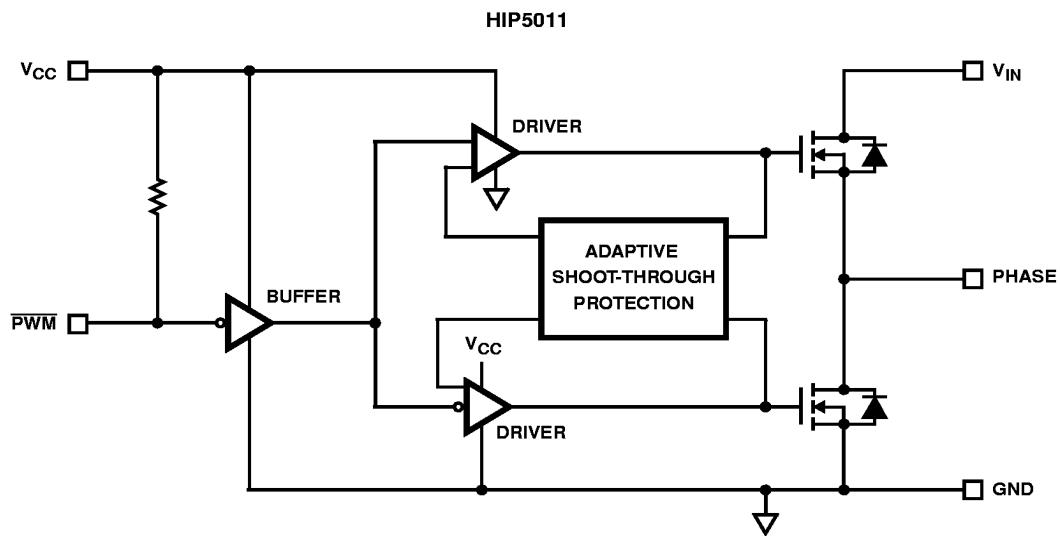
SYNCHRONOUS RECTIFIED BUCK CONVERTER

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PowerPC is a trademark of International Business Machines.
SynchroFET™ is a trademark of Harris Corporation.

Non-Inverting SynchroFET™ Block Diagram



Inverting SynchroFET™ Block Diagram



Absolute Maximum Ratings

| | |
|---|-----------------------|
| Supply Voltage, V _{CC} | +16V |
| Input Voltage V _{IN} | +7V |
| I _{PHASE} , I _{VIN} , I _{GND} (T _J = 25°C) | 17A (Repetitive Peak) |
| I _{PHASE} , I _{VIN} , I _{GND} (T _J = 150°C) | 15A (Repetitive Peak) |
| PWM Input | -4V to +16V |
| ESD Classification | Class 3 (4kV) |
| Lead Temperature (Soldering 10s) (Lead Tips Only) | 300°C |
| Storage Temperature Range | -65°C to 150°C |
| Junction Temperature Range | -40°C to 150°C |

Thermal Information (Typical)

| Package | $\theta_{JC}^{\dagger\dagger}$ (°C/W) | θ_{JA} (°C/W) [†] | | | | |
|---------------------|--|-----------------------------------|----|----|----|------------------|
| | | 0 | 1 | 2 | 3 | 3 ^{†††} |
| SOIC (IB) | 26 | 63 | 45 | 42 | 41 | 35 |
| SIP (IS) | 2 | 55 | 30 | 25 | 24 | 18 |
| SIP (IS1) | 2 | - | - | - | - | - |

[†] Versus additional square inches of 1 ounce copper on the printed circuit board.

^{††} θ_{JC} is measured to pin 12 for the SOIC. Printed circuit board had 1 square inch of copper. For SIP Packages value shown is typical with an infinite heat sink.

^{†††} 200 linear feet per minute of air flow.

CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the recommended operating conditions of this specification is not implied.

Recommended Operating Conditions

| | |
|--|------------|
| Supply Voltage, V _{CC} | +12V, ±20% |
| Input Voltage V _{IN} | 0V to 5.5V |
| Supply Voltage, V _{CC} , minimum for charge-pumped start-up | +4.0V |

I_{PHASE} SIPs:11.5A(RMS), 11.2A(DC); SOIC:7.4A(RMS), 7.4A(DC)
I_{VIN} SIPs:10.0A(RMS), 8.5A(DC); SOIC:6.4A(RMS), 6.4A(DC)
I_{GND} SIPs:8.5A(RMS), 6.0A(DC); SOIC:5.4A(RMS), 5.4A(DC)

Electrical Specifications

| PARAMETERS | SYMBOL | TEST CONDITIONS | T _J = 25°C | | | T _J = -40°C T _J = 150°C | | UNITS |
|---|--------------------|--|-----------------------|-----|-----|--|-----|-------|
| | | | MIN | TYP | MAX | MIN | MAX | |
| r _{DS(ON)} Upper MOSFET | R _{DSU} | V _{CC} = 12V, V _{IN} = 5V | - | 34 | 39 | - | 65 | mΩ |
| r _{DS(ON)} Lower MOSFET | R _{DNL} | V _{CC} = 12V, V _{IN} = 5V | - | 36 | 4 | - | 68 | mΩ |
| V _{IN} Operating Current | I _{VINO} | V _{IN} = 5V, No Load, 500kHz | - | 5 | 8 | - | 10 | mA |
| V _{IN} Quiescent Current | I _{VIN} | PWM or \overline{PWM} = V _{CC} or GND | - | 0.1 | 10 | - | 100 | μA |
| V _{CC} Operating Current | I _{CCO} | V _{CC} = 12V, 500kHz | - | 8 | 12 | - | 15 | mA |
| V _{CC} Quiescent Current (HIP5010) | I _{CCIH} | PWM = V _{CC} | - | 80 | - | - | 400 | μA |
| V _{CC} Quiescent Current (HIP5010) | I _{CCIL} | PWM = GND | - | 0.1 | 10 | - | 100 | μA |
| V _{CC} Quiescent Current (HIP5011) | I _{CCNIH} | \overline{PWM} = V _{CC} | - | 0.1 | 10 | - | 100 | μA |
| V _{CC} Quiescent Current (HIP5011) | I _{CCNIL} | \overline{PWM} = GND | - | 140 | - | - | 400 | μA |
| Low Level PWM Input Voltage | V _{IL} | | - | 1.8 | - | 1 | - | V |
| High Level PWM Input Voltage | V _{IH} | | - | 2.1 | - | - | 3 | V |
| PWM Input Voltage Hysteresis | V _{IHYS} | | - | 0.3 | - | - | - | V |
| Input Pulldown Resistance (HIP5010) | R _{PWM} | | - | 220 | - | 100 | 400 | kΩ |
| Input Pullup Resistance (HIP5011) | R _{PWM} | | - | 220 | - | 100 | 400 | kΩ |

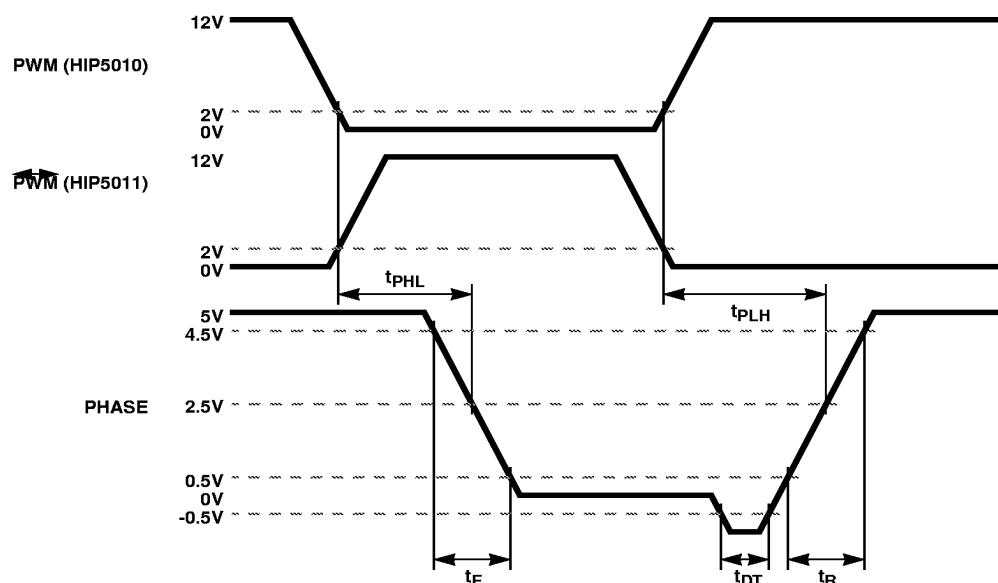
Switching Specifications

| PARAMETERS | SYMBOL | TEST CONDITIONS | T _J = 25°C | | | T _J = -40°C T _J = 150°C | | UNITS |
|-----------------------------|------------------|--|-----------------------|-----|-----|--|-----|-------|
| | | | MIN | TYP | MAX | MIN | MAX | |
| Upper Device Turn-Off Delay | t _{PHL} | V _{CC} = 12V, I _{PHASE} = -1A | - | 30 | 50 | - | 80 | ns |
| Lower Device Turn-Off Delay | t _{PPL} | V _{CC} = 12V, I _{PHASE} = +1A | - | 30 | 50 | - | 80 | ns |
| Dead Time | t _{DT} | V _{CC} = +12V, I _{PHASE} = -1A | - | 10 | - | - | - | ns |
| Phase Rise-Time | t _R | V _{CC} = 12V, I _{PHASE} = -1A | - | 20 | - | - | - | ns |
| Phase Fall-Time | t _F | V _{CC} = 12V, I _{PHASE} = +1A | - | 20 | - | - | - | ns |

Pin Descriptions

| SYMBOL | DESCRIPTION |
|--------------------------------|--|
| V _{CC} | Positive supply to control logic and gate drivers. De-couple this pin to GND. |
| V _{IN} | FET Switch Input Voltage. De-couple this pin to GND. Tie all V _{IN} terminals together. |
| PHASE | Output. Tie all phase terminals together. |
| PWM (HIP5010) PWM (HIP5011) | Single Ended Control Input. This input connects to the PWM controller output. |
| GND | System Ground. |

Timing Diagram



NOTE: I_{PHASE} = +1A for t_{PLH} and t_F, I_{PHASE} = -1A for t_{PHL}, t_{DT}, and t_R.

FIGURE 1.

Typical Performance Curves

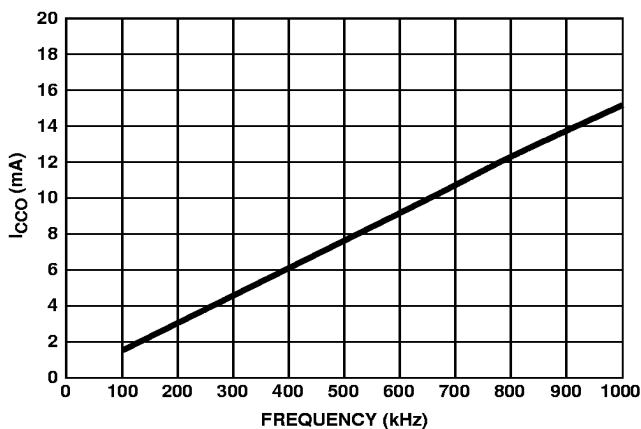


FIGURE 2. I_{CCO} vs FREQUENCY

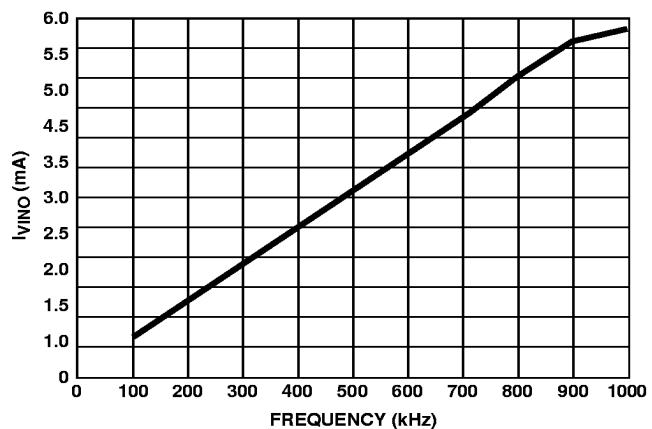


FIGURE 3. I_{VINO} vs FREQUENCY

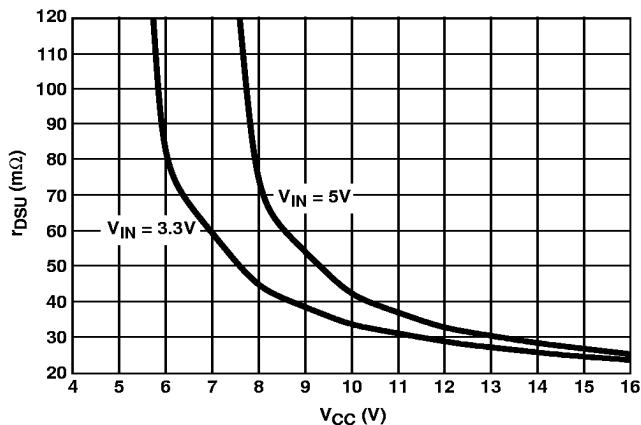


FIGURE 4. R_{DSU} vs V_{CC}

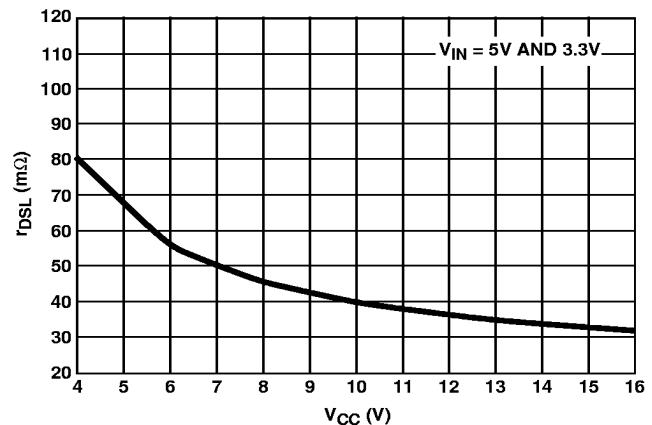


FIGURE 5. R_{DSL} vs V_{CC}

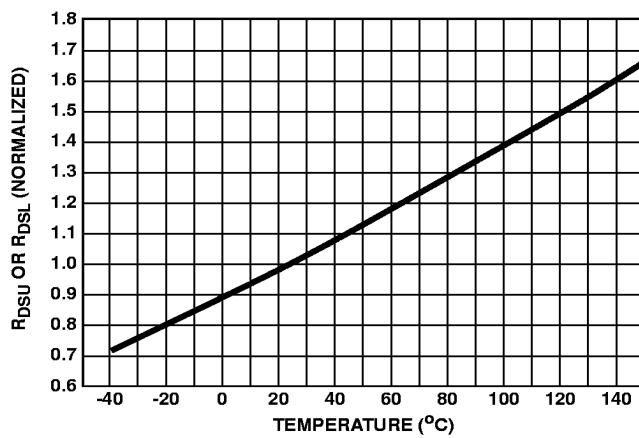
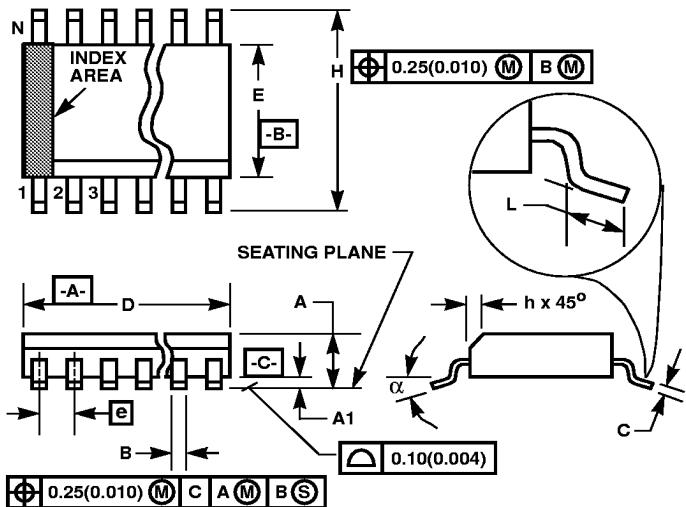


FIGURE 6. R_{DSU} OR R_{DSL} vs TEMPERATURE

Small Outline Plastic Packages (SOIC)

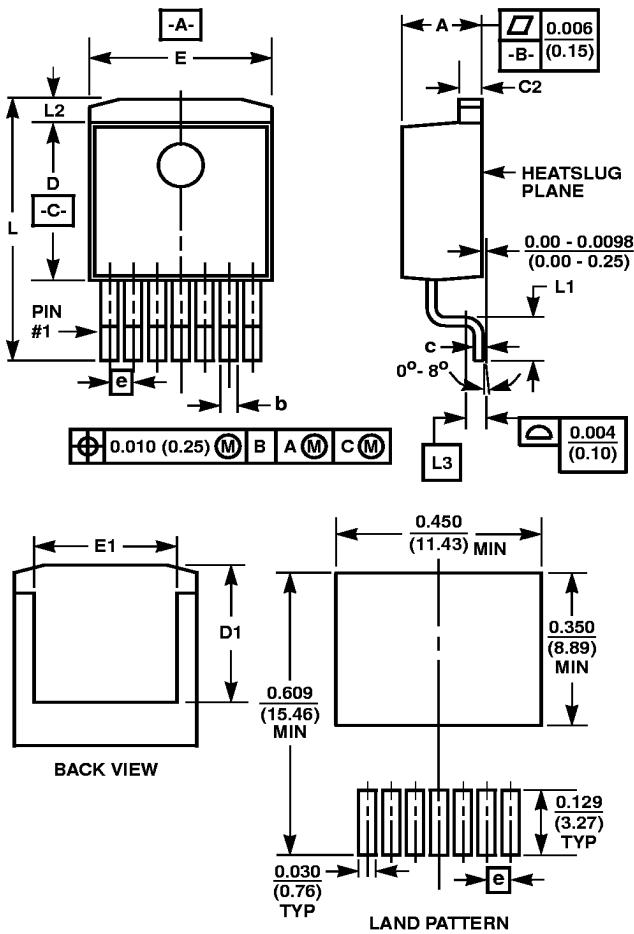
NOTES:

1. Symbols are defined in the "MO Series Symbol List" in Section 2.2 of Publication Number 95.
2. Dimensioning and tolerancing per ANSI Y14.5M-1982.
3. Dimension "D" does not include mold flash, protrusions or gate burrs. Mold flash, protrusion and gate burrs shall not exceed 0.15mm (0.006 inch) per side.
4. Dimension "E" does not include interlead flash or protrusions. Interlead flash and protrusions shall not exceed 0.25mm (0.010 inch) per side.
5. The chamfer on the body is optional. If it is not present, a visual index feature must be located within the crosshatched area.
6. "L" is the length of terminal for soldering to a substrate.
7. "N" is the number of terminal positions.
8. Terminal numbers are shown for reference only.
9. The lead width "B", as measured 0.36mm (0.014 inch) or greater above the seating plane, shall not exceed a maximum value of 0.61mm (0.024 inch)
10. Controlling dimension: MILLIMETER. Converted inch dimensions are not necessarily exact.

**M16.3 (JEDEC MS-013-AA ISSUE C)
16 LEAD WIDE BODY SMALL OUTLINE PLASTIC PACKAGE**

| SYMBOL | INCHES | | MILLIMETERS | | NOTES |
|----------|-----------|-----------|-------------|-----------|-------|
| | MIN | MAX | MIN | MAX | |
| A | 0.0926 | 0.1043 | 2.35 | 2.65 | - |
| A1 | 0.0040 | 0.0118 | 0.10 | 0.30 | - |
| B | 0.013 | 0.0200 | 0.33 | 0.51 | 9 |
| C | 0.0091 | 0.0125 | 0.23 | 0.32 | - |
| D | 0.3977 | 0.4133 | 10.10 | 10.50 | 3 |
| E | 0.2914 | 0.2992 | 7.40 | 7.60 | 4 |
| e | 0.050 BSC | | 1.27 BSC | | - |
| H | 0.394 | 0.419 | 10.00 | 10.65 | - |
| h | 0.010 | 0.029 | 0.25 | 0.75 | 5 |
| L | 0.016 | 0.050 | 0.40 | 1.27 | 6 |
| N | 16 | | 16 | | 7 |
| α | 0° | 8° | 0° | 8° | - |

Rev. 0 12/93

Single-In-Line Plastic Packages (SIP)**Z7.05B**

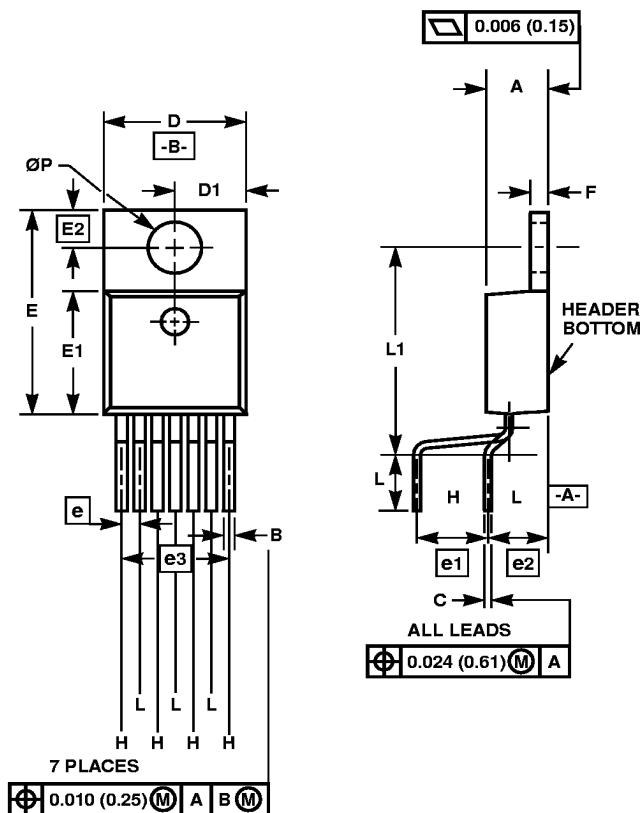
7 LEAD PLASTIC SINGLE-IN-LINE PACKAGE SURFACE MOUNT
“GULLWING” LEAD FORM

| SYMBOL | INCHES | | MILLIMETERS | | NOTES |
|--------|-----------|-------|-------------|-------|---------|
| | MIN | MAX | MIN | MAX | |
| A | 0.170 | 0.180 | 4.32 | 4.57 | - |
| C2 | 0.048 | 0.055 | 1.22 | 1.39 | 5 |
| D | 0.350 | 0.370 | 8.89 | 9.39 | - |
| E | 0.395 | 0.405 | 10.04 | 10.28 | - |
| D1 | 0.310 | - | 7.88 | - | - |
| E1 | 0.310 | - | 7.88 | - | - |
| L | 0.549 | 0.569 | 13.95 | 14.45 | - |
| L1 | 0.068 | 0.088 | 1.72 | 2.24 | - |
| L2 | 0.045 | 0.055 | 1.15 | 1.40 | - |
| L3 | 0.030 BSC | | 0.76 BSC | | 4 |
| b | 0.028 | 0.034 | 0.71 | 0.86 | 5, 6, 7 |
| c | 0.018 | 0.024 | 0.46 | 0.60 | 5 |
| e | 0.050 BSC | | 1.27 BSC | | - |

Rev. 2 12/95

NOTES:

1. These package dimensions are within allowable dimensions of JEDEC MO-169AC, Issue A.
2. Controlling dimension: Inch.
3. Dimensioning and tolerance per ANSI Y14.5M-1982.
4. Gauge plane L3 is parallel to heatslug plane.
5. Dimensions include lead finish.
6. Leads are not allowed above the datum [-B-].
7. Dimension "b" does not include dambar protrusion. Allowable dambar protrusion shall not cause the lead width to exceed the maximum "b" by more than 0.003" (0.08mm).

Single-In-Line Plastic Packages (SIP)**Z7.05C**

7 LEAD PLASTIC SINGLE-IN-LINE PACKAGE STAGGERED VERTICAL LEAD FORM

| SYMBOL | INCHES | | MILLIMETERS | | NOTES |
|--------|-----------|-------|-------------|-------|-------|
| | MIN | MAX | MIN | MAX | |
| A | 0.170 | 0.180 | 4.32 | 4.57 | - |
| B | 0.028 | 0.034 | 0.71 | 0.86 | 3, 4 |
| C | 0.018 | 0.024 | 0.46 | 0.60 | 3 |
| D | 0.395 | 0.405 | 10.04 | 10.28 | - |
| D1 | 0.198 | 0.202 | 5.03 | 5.13 | - |
| E | 0.595 | 0.605 | 15.11 | 15.37 | - |
| E1 | 0.350 | 0.370 | 8.89 | 9.39 | - |
| E2 | 0.110 BSC | | 2.79 BSC | | |
| e | 0.050 BSC | | 1.27 BSC | | - |
| e1 | 0.200 BSC | | 5.08 BSC | | - |
| e2 | 0.169 BSC | | 4.29 BSC | | - |
| e3 | 0.300 BSC | | 7.62 BSC | | - |
| F | 0.048 | 0.055 | 1.22 | 1.39 | 3 |
| L | 0.150 | 0.176 | 3.81 | 4.47 | - |
| L1 | 0.600 | 0.620 | 15.24 | 15.74 | - |
| ØP | 0.147 | 0.152 | 3.73 | 3.86 | 3 |

Rev. 1 4/98

NOTES:

1. Controlling dimension: INCH.
2. Dimensioning and tolerancing per ANSI Y14.5M-1982.
3. Dimensions include lead finish.
4. Dimension "B" does not include dambar protrusion. Allowable dambar protrusion shall not cause lead width to exceed maximum "B" by more than 0.003 inches (0.08mm).

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